



VCx-850C2WA

850nm 2000mW CW VCSEL Diode

Data Sheet

Features

- 850nm VCSEL diode
- Output power: 2000mW (CW)
- Good thermal conduction
- Oxide isolation technology
- Available in SMD 7060 or T-mount package options

Applications

- 3D sensing
- LiDAR (Light Detection and Ranging)
- Infrared (IR) illumination
- Proximity sensors
- Medical imaging and treatment systems

Ordering Information

Part Number	Description
VC70C-850C2WA	850nm 2000mW CW VCSEL Diode, SMD 7060 Package
VCTMC-850C2WA	850nm 2000mW CW VCSEL Diode, T-Mount Package

* Additional package configurations may be available upon request.

Absolute Maximum Ratings

Parameters	Symbol	Rating	Unit	Conditions
Case Operating Temperature	Top	-40 to 85	°C	
Storage Temperature	Tstg	-40 to 105	°C	
Reflow Soldering Temperature	Tsol	260	°C	10 seconds
Reverse Voltage	Vr	5	V	
Maximum Continuous Current	I _{max}	4	A	
ESD Exposure (Human Body) Model	ESD	2k-4k	V	Class 2
ESD Exposure (Machine) Model	ESD	200-400	V	Class B

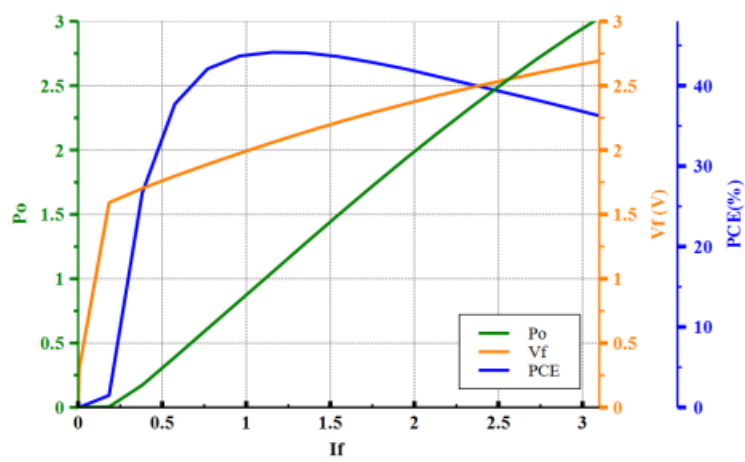
Electrical-Optical Characteristics (T_{op}=25°C, CW Mode)

Parameters	Symbol	Min.	Typ.	Max.	Unit	Conditions
Optical Output Power	P _o	-	2000	-	mW	I _F =2.04A
Threshold Current	I _{th}	-	0.25	-	A	
Forward Current	I _F	-	2.04	-	A	
Slope Efficiency	η	-	1.04	-	W/A	P _o =2000mW
Power Conversion Efficiency	PCE	-	41	-	%	I _F =2.04A
Peak Wavelength	λ _P	840	850	860	nm	I _F =2.04A
Laser Forward Voltage	V _F	-	2.38	-	V	I _F =2.04A
Series Resistance	R _S	-	0.33	-	Ω	I _F =2.04A
Beam Divergence	FWHM _B	-	20	-	deg	
Wavelength Temperature Drift	Δλ _P / ΔT	-	0.07	-	nm/°C	I _F =2.04A
Emission Area			702x524		um ²	
No. of Emission Aperture			306			

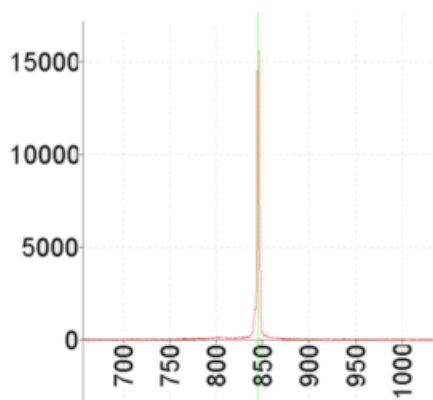
Note: Electro-optical characteristic with a package or diffuser would require further evaluation. Values are based on limited sample size and estimated values.

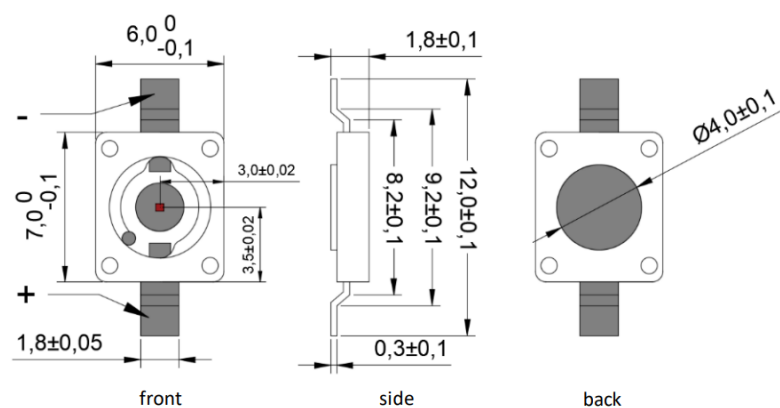
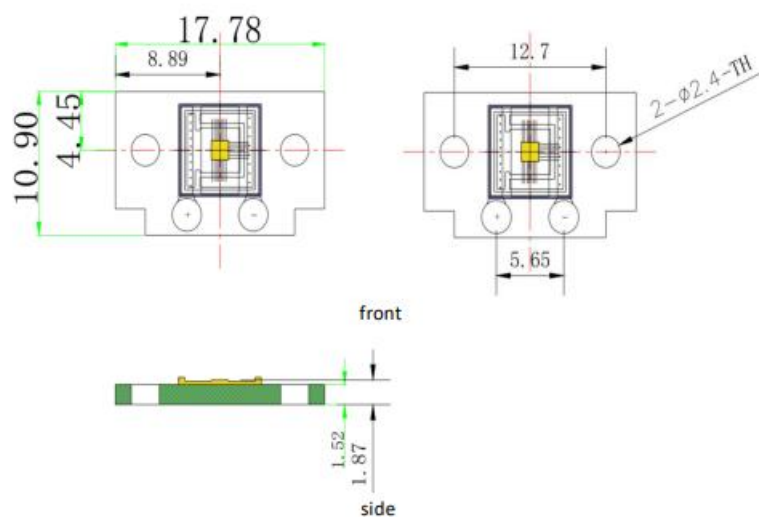
Typical Characteristics

LIV Graph

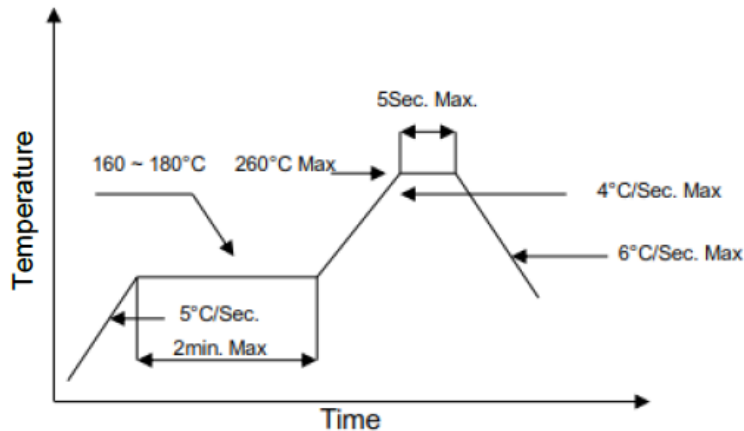


Intensity vs. Wavelength



Outline Dimensions (unit: mm)**SMD 7060 Package****T-Mount Package**

SMT Reflow Soldering Curve



Note: Reflow soldering can be operated only one time. During the temperature ramp-up, no forces may be exerted on the LD which would deform or damage them. After soldering is completed, please do not process until the product temperature ramps down to room temperature.

Additional Notes

1. Stresses exceeding those listed in Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress limits only and do not imply functional operation under such conditions. Exposure to conditions beyond recommended operating limits may affect device reliability.
2. Operation at or near maximum ratings may degrade performance and may create potential safety risks, including device failure.
3. The device is sensitive to electrostatic discharge (ESD). Proper ESD precautions, including grounded wrist straps, antistatic work surfaces, and ESD-safe handling procedures, must be followed during handling and assembly.
4. Adequate thermal management must be provided. The VCSEL device should be properly mounted to ensure efficient heat transfer to the package or system thermal path to maintain stable optical performance.
5. Avoid direct exposure of laser radiation to human eyes or skin. Follow applicable laser safety regulations and system-level safety design practices.
6. The emitting surface of the VCSEL should not be touched or contaminated. Mechanical contact or contamination may degrade optical performance or damage the device.
7. Use appropriate pick-and-place handling tools, such as ceramic or ESD-safe vacuum nozzles, to prevent mechanical or electrostatic damage during assembly.
8. Specifications are subject to change without notice.